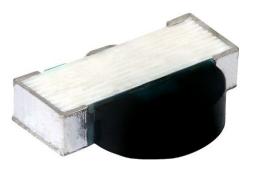
VEMD11940FX01

Vishay Semiconductors



Silicon PIN Photodiode



DESCRIPTION

VEMD11940FX01 is a high speed and high sensitive PIN photodiode in a miniature side looking, surface mount package (SMD) with daylight blocking filter. Filter is matched with IR emitters operating at wavelength of 830 nm to 950 nm. The photo sensitive area of the chip is 0.053 mm².

FEATURES

- · Package type: surface mount
- Package form: Side view
- Dimensions (L x W x H in mm): 3 x 2 x 0.6
- AEC-Q101 qualified
- High radiant sensitivity
- Daylight blocking filter matched with 830 nm to 950 nm IR emitters
- Angle of half sensitivity: $\varphi = \pm 75^{\circ}$
- Package matched with IR emitter VSMB11940X01
- Floor life: 168 h, MSL 3, according to J-STD-020
- · Lead (Pb)-free reflow soldering
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- High speed photo detector
- Infrared remote control
- Infrared data transmission
- Photo interrupters
- IR touch panels

PRODUCT SUMMARY				
COMPONENT	I _{ra} (μΑ)	φ (deg)	λ _{0.5} (nm)	
VEMD11940FX01	1.13	± 75	780 to 1050	

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VEMD11940FX01	Tape and reel	MOQ: 4000 pcs, 4000 pcs/reel	Side view		

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	60	V	
Power dissipation	T _{amb} ≤ 25 °C	Pv	104	mW	
Junction temperature		Тj	100	°C	
Operating temperature range		T _{amb}	-40 to +100	°C	
Storage temperature range		T _{stg}	-40 to +100	°C	
Soldering temperature	According to reflow solder profile fig. 8	T _{sd}	260	°C	
Thermal resistance junction / ambient	According to J-STD-051	R _{thJA}	580	K/W	



HALOGEN

VEMD11940FX01



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BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 50 mA	V _F	-	1.7	-	V
Breakdown voltage	I _R = 100 μA, E = 0	V _(BR)	32	-	-	V
Reverse dark current	V _R = 10 V, E = 0	I _{ro}	-	<1	10	nA
Diode capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	CD	-	1.1	-	pF
	$V_{R} = 3 V, f = 1 MHz, E = 0$	CD	-	0.5	-	pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$	Vo	-	350	-	mV
Temperature coefficient of V_o	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$	TK _{Vo}	-	-2.7	-	mV/K
Short circuit current	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$	I _k	-	1.13	-	μA
Temperature coefficient of I_k	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$	TK _{lk}	-	0.1	-	%/K
Reverse light current	$E_e=1~mW/cm^2,\lambda=950~nm,V_R=5~V$	I _{ra}	0.8	1.13	1.8	μA
Angle of half sensitivity		φ	-	± 75	-	deg
Wavelength of peak sensitivity		λ _p	-	950	-	nm
Range of spectral bandwidth		λ _{0.5}	-	780 to 1050	-	nm
Rise time	V_R = 10 V, R_L = 1 k Ω , λ = 820 nm	t _r	-	100	-	ns
Fall time	V_R = 10 V, R_L = 1 k Ω , λ = 820 nm	t _f	-	100	-	ns

BASIC CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

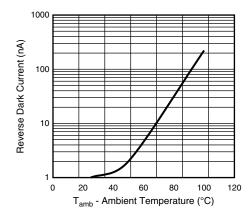


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

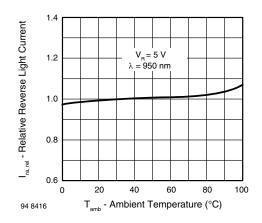


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

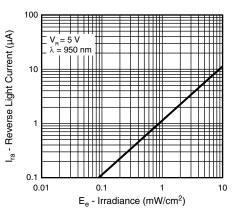
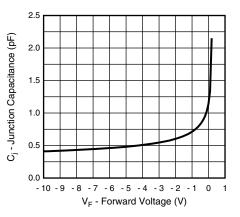


Fig. 3 - Reverse Light Current vs. Irradiance





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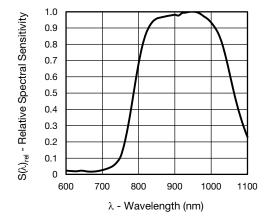


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

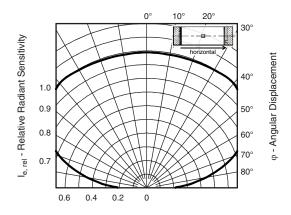
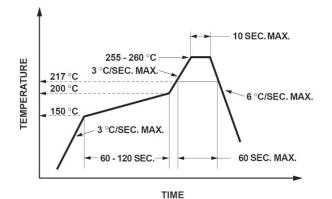
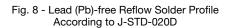


Fig. 6 - Relative Radiant Sensitivity vs. Angular Displacement -Horizontal

REFLOW SOLDER PROFILE







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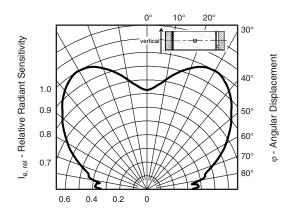


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement - Vertical

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 168 h

Conditions: T_{amb} < 30 °C, RH < 60 %

Moisture sensitivity level 3, according to J-STD-020.

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

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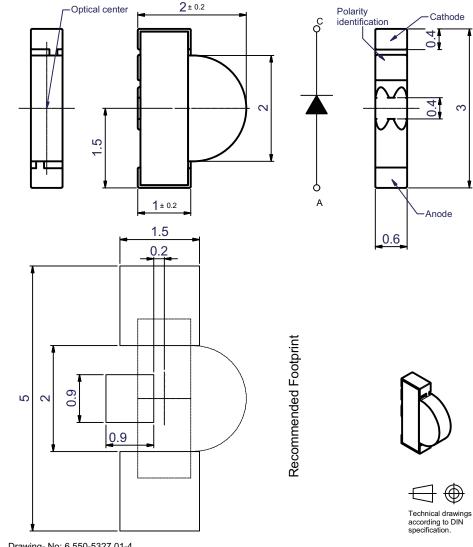


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PACKAGE DIMENSIONS in millimeters



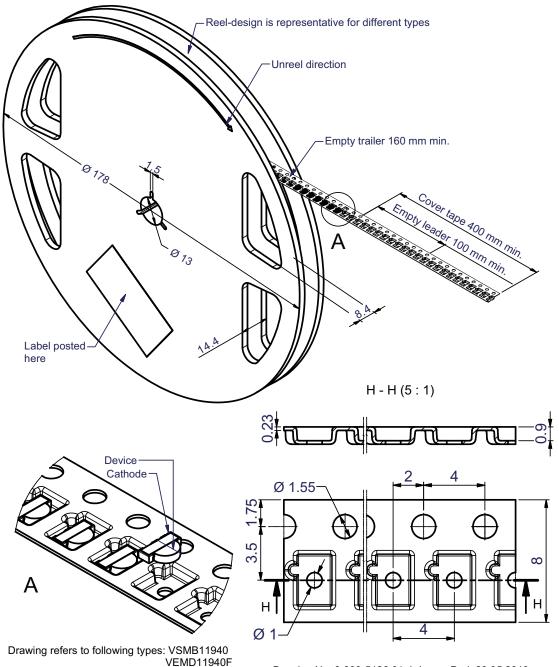
Drawing- No: 6.550-5327.01-4 Issue: Prel. 26.11.2013

Not indicated tolerances ± 0.1 mm

WISHAY. www.vishay.com

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TAPING AND REEL DIMENSIONS in millimeters



Drawing No. 9.800-5126.01-4; Issue: Prel. 23.05.2013



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